

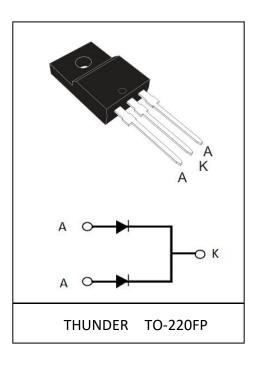
#### **Thunder High Power Products**

# FRED Ultrafast Soft Recovery Diode, 12A

#### **Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

| Product Summary |      |
|-----------------|------|
| VR              | 200V |
| IF(AV)          | 2*6A |
| trr             | 20ns |



## **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

### **Absolute Maximum Ratings**

| Parameter                          | Symbol | Test Conditions    | Values      | Units |
|------------------------------------|--------|--------------------|-------------|-------|
| Repetitive peak reverse voltage    | Vrrm   |                    | 200         | V     |
| Continuous forward current         | lf(AV) | Tc =110°C          | 12          |       |
| Single pulse forward current       | İFSM   | Tc =25°C           | 72          | А     |
| Maximum repetitive forward current | IFRM   | Square wave, 20kHZ | 64          |       |
| Operating junction                 | Tj     |                    | 175         | °C    |
| Storage temperatures               | Tstg   |                    | -55 to +175 | °C    |

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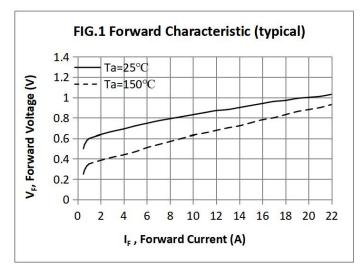


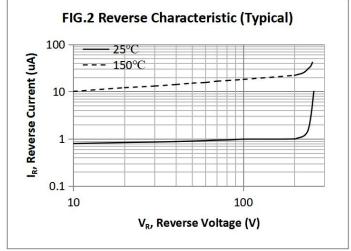
| Parameter                             | Symbol                 | Test Conditions  | Min | Тур. | Max. | Units |
|---------------------------------------|------------------------|--|-----|------|------|-------|
| Breakdown voltage<br>Blocking voltage | VBR,<br>V <sub>R</sub> | Ir=100µA   | 200 |      |      |       |
| Forward voltage<br>(Per Diode)        | 1/-                    | Ir=6A  |     | 0.9  | 1.1  | V     |
|                                       | VF                     | IF=6A, Tj =125°C   |     | 0.8  | 1.0  |       |
| Reverse leakage                       |                        | Vr= Vrrm   |     |      | 10   |       |
| current(Per Diode)                    | Tj=150°C, Vr=200V      |  |     | 100  | μΑ   |       |
| Reverse recovery<br>time(Per Diode)   |                        | I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A |     | 25   | 35   |       |
|                                       |                        | I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us   |     | 20   | 30   | ns    |

#### **Thermal characteristics**

| Paramter         | Symbol         | Тур | Units |
|------------------|----------------|-----|-------|
| Junction-to-Case | $R_{	heta JC}$ | 4.2 | °C/W  |

## **Electrical performance (typical)**

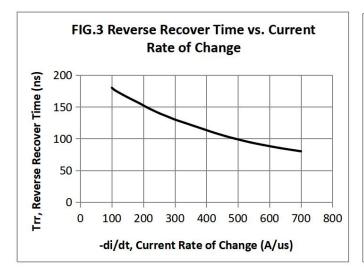


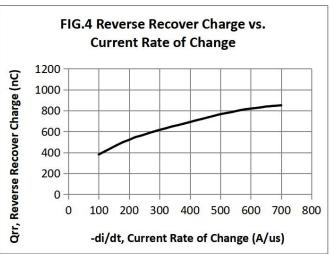


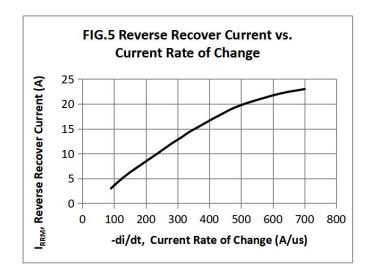
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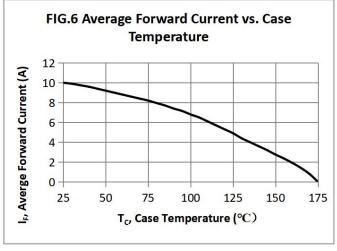


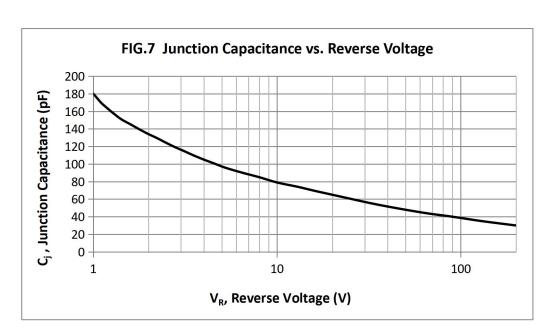












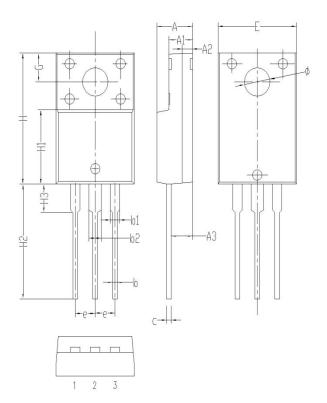
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#### **Package Information**





| Symbol | Dimensions(millimeters |       |
|--------|------------------------|-------|
| Symbol | Min.                   | Max.  |
| Α      | 4.30                   | 4.70  |
| A1     | 2.80                   | 3.20  |
| A2     | 1.10                   | 1.50  |
| A3     | 2.50                   | 2.90  |
| b      | 0.50                   | 0.75  |
| b1     | 1.10                   | 1.35  |
| b2     | 1.50                   | 1.75  |
| С      | 0.45                   | 0.75  |
| е      | 2.34                   | 2.7   |
| Е      | 9.85                   | 10.45 |
| Н      | 14.8                   | 15.0  |
| H1     | 8.30                   | 8.70  |
| H2     | 12.7                   | 13.7  |
| H3     | 3.10                   | 3.50  |
| G      | 2.50                   | 2.90  |
| ΦР     | 3.10                   | 3.40  |

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#### -Headquarters

WuXi Thunder Microelectronics Incorporated Limited

Building E1-9F, No.200 LingHu Road, XinWu district, WuXi, China 214135

Tel:+86-510-85160109 Fax:+86-510-85160109

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